

February 1995

DH0035/DH0035C PIN Diode Driver

General Description

The DH0035/DH0035C is a high speed digital driver designed to drive PIN diodes in RF modulators and switches. The device is used in conjunction with an input buffer such as the DM7830/DM8830 or DM5440/DM7440.

Features

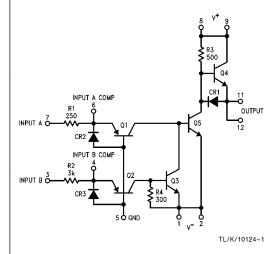
- Large output voltage swing—30V
- Peak output current in excess of 1A
- Inputs TTL/DTL compatible

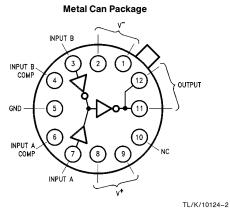
- Short propagation delay—10 ns
- High repetition rate—5 MHz

The DH0035/DH0035C is capable of driving a variety of PIN diode types including parallel, serial, anode grounded and cathode grounded. For additional information, see *AN-49 PIN Diode Drivers*.

The DH0035 is guaranteed over the temperature range -55°C to $+125^{\circ}\text{C}$ whereas the DH0035C is guaranteed from 0°C to $+85^{\circ}\text{C}.$

Schematic and Connection Diagrams





Top View

Order Number DH0035G-MIL or DH0035CG See NS Package Number G12B

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Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

V $^-$ Supply Voltage Differential (Pin 5 to Pin 1 or 2) 40V V $^+$ Supply Voltage Differential (Pin 1 or 2 to Pin 8 or 9) 30V Input Current (Pin 3 or 7) \pm 75 mA Peak Output Current \pm 1.0A

 Power Dissipation (Note 3)
 1.5W

 Storage Temperature Range
 -65°C to +150°C

 Operating Temperature Range
 -55°C to +125°C

 DH0035
 0°C to +85°C

 Lead Temperature (Soldering, 10 sec.)
 300°C

Electrical Characteristics (Notes 1 and 2)

Parameter	Conditions	Limits			Units
		Min	Тур	Max	Onits
Input Logic "1" Threshold	$V_{OUT}=-8V,R_L=100\Omega$		1.0	2.0	V
Input Logic "0" Threshold	$V_{OUT}=+8V$, $R_{L}=100\Omega$	0.4	0.6		V
Positive Output Swing	I _{OUT} = 100 mA	7.0	+8.0		V
Negative Output Swing	I _{OUT} = 100 mA		-8.0	-7.0	V
Positive Short Circuit Current	$V_{\text{IN}} = 0$ V, $R_{\text{L}} = 0$ Ω (Pulse Test, Duty Cycle ≤ 3 %)	400	800		mA
Negative Short Circuit Current	$V_{\text{IN}}=$ 1.5V, $I_{\text{IN}}=$ 50 mA, $R_{\text{L}}=$ 0 Ω (Pulse Test, Duty Cycle \leq 3%)	800	1000		mA
Turn-On Delay	$V_{IN} = 1.5V, V_{OUT} = -3V$		10	15	ns
Turn-Off Delay	$V_{IN} = 1.5V, V_{OUT} = +3V$		15	30	ns
On Supply Current	V _{IN} = 1.5V		45	60	mA

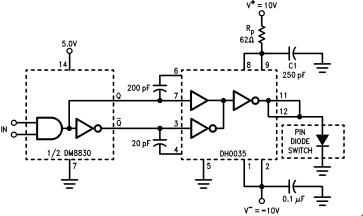
Note 1: Unless otherwise specified, these specifications apply for $V^+ = 10.0V$, $V^- = -10.0V$, pin 5 grounded, over the temperature range -55° C to $+125^{\circ}$ C for the DH0035, and 0° C to $+85^{\circ}$ C for the DH0035C.

Note 2: All typical values are for $T_A = 25$ °C.

Note 3: Derate linearly at 10 mW/°C for ambient temperatures above 25°C.

Typical Applications

Grounded Cathode Design

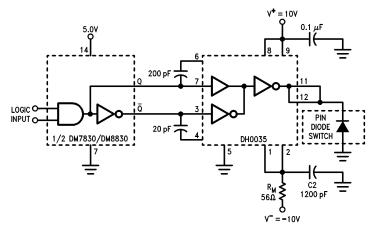


TL/K/10124-3

Note: Cathode grounded PIN diode: $R_p=62\Omega$ limits diode forward current to 100 mA. Typical switching for HP33604A, RF turn-on 25 ns, turn-off 5 ns. C2 = 250 pF, $R_p=0\Omega$, C1 = 0.1F.

Typical Applications (Continued)

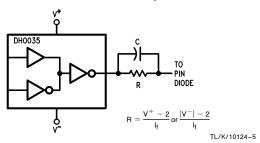
Grounded Anode Design



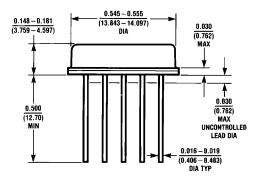
TL/K/10124-4

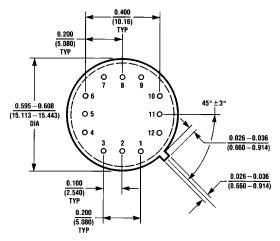
Note: Anode Grounded PIN diode: $R_M=56\Omega$ limits diode forward current to 100 mA. Typical switching for HP33622A, RF turn-on 5 ns; turn-off 4 ns. C1 = 470 pF, C2 = 0.1 μ F, $R_M=0\Omega$.

Alternate Current Limiting



Physical Dimensions inches (millimeters)





G12B (REV C)

12 Lead Metal Can Package Order Number DH0035G-MIL or DH0035CG NS Package Number G12B

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